LS
(Ref.: SG9-TD376-R1)

Source: ITU-T Study Group 9
Title: LS on the new work item on J.Sup-HiNoC and the progress on J.HiNoC3-PHY and J.HiNoC3-MAC

LIAISON STATEMENT

For action to: -
For information to: ITU-T SG15, ETSI TC Cable, IEC TC100, CableLabs, SCTE, TTA, TTC, IEEE 802.3 Ethernet WG, CCSA.
Approval: ITU-T Study Group 9 meeting (Bangalore, 18 May 2023)
Deadline: N/A

Contact: Satoshi Miyaji
KDDI Corporation
Japan
Tel: +81 3 6678 3542
E-mail: [redacted]

Contact: Cui Zhao
ABS, NRTA
China
Tel: +86-10-86098037
E-mail: [redacted]

Abstract: This liaison statement informs ITU-T SG15, ETSI TC Cable, IEC TC100, CableLabs, SCTE, TTA, TTC, IEEE 802.3 Ethernet WG, and CCSA of the new work item on J.Sup-HiNoC.

ITU-T Study Group 9 is pleased to inform you that during its meeting held on 9-18 May 2023, Bangalore, India, SG9 has initiated a new work item, candidate to be published as ITU-T Supplement, on J.Sup-HiNoC “Comparison between third-generation HiNoC and second-generation HiNoC”. Also SG9 would like to inform you on the latest progress on the draft Recommendations J.HiNoC3-PHY and J.HiNoC3-MAC.

SG9 would be pleased to hear any feedback on the attached documents, which are the current drafts of the new work item and the ongoing work items related to HiNoC3.

We look forward to a continued collaboration with your groups.

Attachments:
1. SG9-TD375-R1: Output - Draft new ITU-T Supplement J.Sub-HiNoC "Comparison between third-generation HiNoC and second-generation HiNoC"
2. SG9-TD373: Output - Draft new Recommendation ITU-T J.HiNoC3-PHY "Physical layer specification for third-generation HiNoC"
3. SG9-TD374: Output - Draft new Recommendation ITU-T J.HiNoC3-MAC "MAC layer specification for third-generation HiNoC"